



## **PNP Epitaxial Silicon Transistor**

Absolute Maximum Ratings T<sub>a</sub>=25°C unless otherwise noted

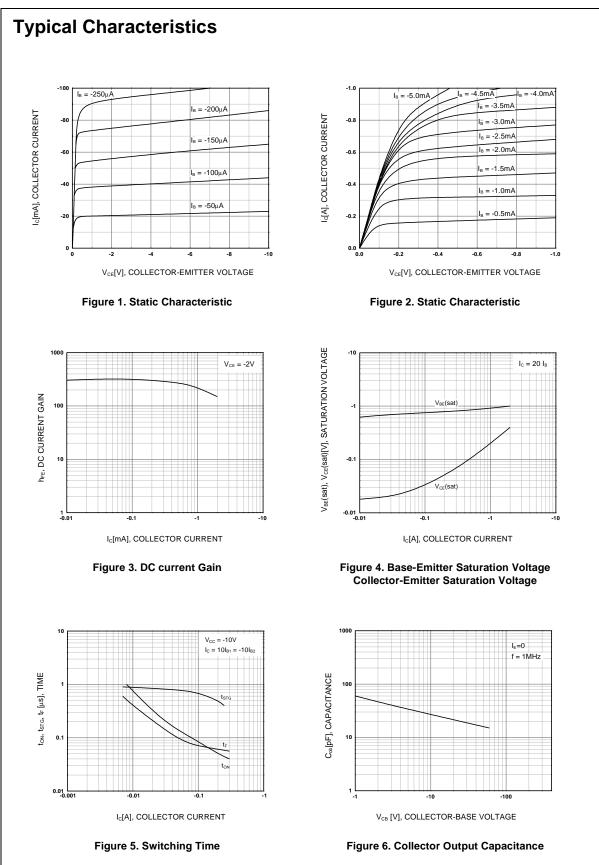
ibol Parameter Parameter		Ratings	Units	
	Collector-Base Voltage	-60	V	
	Collector-Emitter Voltage	-50	V	
-	Emitter-Base Voltage	-6	V	
	Collector Current (DC)	-1	А	
1. 1.	* Collector Current (Pulse)	-2	А	
Collector Power Dissipation		0.75	W	
Junction Temperature		150	°C	
	Storage Temperature	-55 ~ 150	°C	
Duty Cycles	≤50%		A750-	
	≤50%	HE	WWW	

## Electrical Characteristics Ta=25°C unless otherwise noted

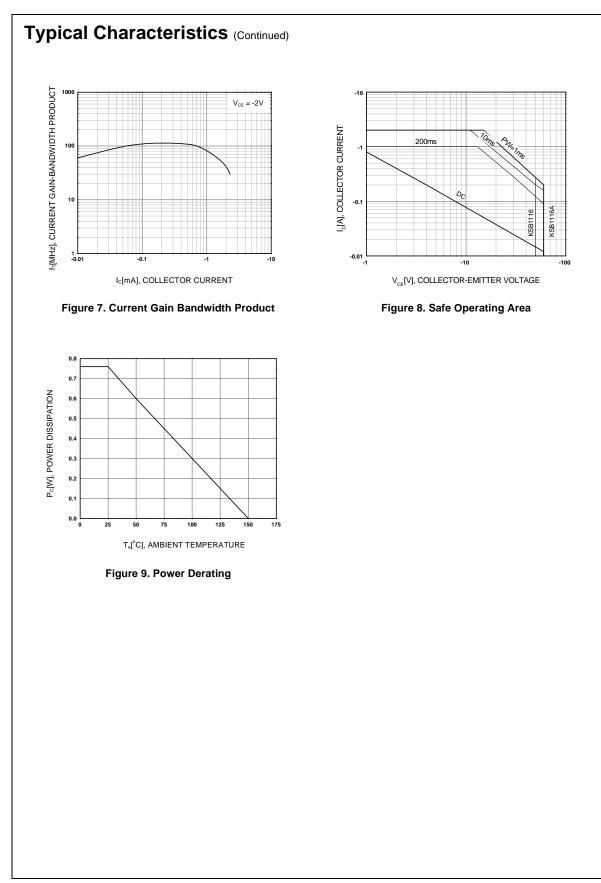
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -60V, I <sub>E</sub> =0			-100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -6V, I_{C} = 0$			-100	nA
h <sub>FE1</sub> h <sub>FE2</sub>	* DC Current Gain	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA V <sub>CE</sub> = -2V, I <sub>C</sub> = -1A	135 81		600	
V <sub>BE</sub> (on)	* Base-Emitter On Voltage	V <sub>CE</sub> = -2V, I <sub>C</sub> = -50mA	-600	-650	-700	mV
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA		-0.2	-0.3	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA		-0.9	-1.2	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0, f=1MHz		25		pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA	70	120	100	MHz
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = -10V, I <sub>C</sub> = -100mA		0.07		μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = -10mA$		0.7		μs
t <sub>F</sub>	Fall Time	$V_{BE}$ (off)= 2~3V		0.07		μs

\* Pulse Test: PW ≤350µs, Duty Cycle≤2%

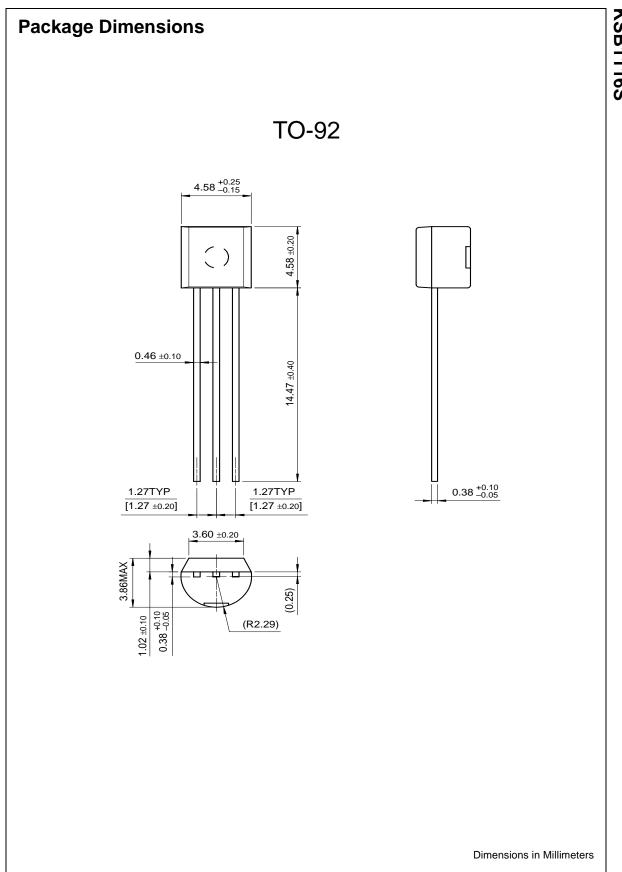
* Pulse Test: PW ≤350µs, Duty Cycle≤2%						
h <sub>FE</sub> Classification						
Cla	ssification	Y	G	L		
0 70 -	h <sub>FE1</sub>	135 ~ 270	200 ~ 400	300 ~ 600		



## KSB1116S



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